# Wireless Power Transfer Using Resonant Inductive Coupling for 3D Integrated ICs

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Abstract- In this paper we introduce a wireless power transfer scheme using resonant inductive coupling for 3DICs to enhance power transfer efficiency and power transfer density with smaller coils. Numerical analysis and optimal conditions are presented for both power transfer efficiency and density. HFSS simulation results are shown to verify the theoretical results. Coils for the power link are designed using a Chartered 0.13µm CMOS process. The peak power transfer efficiency is 52% and power transfer density is 49mW/mm<sup>2</sup>.

# I. INTRODUCTION

3D integration is a promising solution for shortening interconnect in parallel processing in order to achieve smaller form-factor and higher performance. Several wired and wireless methods have been proposed to implement data communication among vertically stacked ICs in a package [1,2]. However, only wired methods such as wire-bonding or micro-bumps have been used for the power supply, even though wireless power delivery has unique advantages in 3DIC applications. It can eliminate the Known-Good-Die (KGD) issues to improve the yield, and some MEMS applications require non-contact power transfer [3], which can be realized by wireless power transfer. Fig. 1 illustrates two examples of systems requiring wireless power transfer.

Previous work has reported wireless power transmission between two inductively coupled coils in stacked dies within a package [4]. This uses standard inductive coupling which results in relatively low power efficiency (<30%) and large coils ( $700x700\mu$ m) since most of flux is not linked between the coils. The resonance of an inductively coupled system increases the amount of magnetic flux linked between coils and improves the power transmission significantly [5]. In this paper, we will introduce wireless power transfer using resonant inductive coupling for 3DICs to increase power transfer efficiency and density with smaller coils.

The paper is organized as follows; In Section II, we will discuss power transfer efficiency. The optimal condition and numerical analysis on maximum power transfer efficiency will be introduced. Section III discusses power transfer density. In IC designs, silicon area is always a major concern. Therefore, power density is sometimes more critical than power efficiency inside a package. We will discuss the optimal values for coil size, load resistance, and coupling coefficient k for maximum



Fig. 1. The applications of wireless power transfer using inductive coupling: (a) Vertical stacking of heterogeneous processes such as logic and DRAM (b) Information Tethered Micro Automated Rotary Stages (ITMARS). Sensors and communication link are integrated on a rotating stage in a substrate.

power transfer density. Section IV will show the coil design for an inductive power link and the simulation results of power efficiency and density. Section V concludes the paper.

# II. POWER TRANSFER EFFICIENCY

## A. Equivalent Circuit

Fig. 2 shows the concept of an inductive power link and its equivalent circuit. The RF input signal with a power amplifier in the transmitter is modeled as a voltage source in the primary resonator. The receiver is modeled as a resister  $R_L$  in the secondary resonator. k is the transformer coupling coefficient, and  $L_1$  and  $L_2$  are self-inductance in transmitter and receiver coils, respectively.  $R_1$  and  $R_2$  model the losses in the coils.  $C_1$  and  $C_2$  are capacitors including parasitic and external capacitance to create a resonance at the transmitter and receiver side. Standard inductive coupling uses a frequency well below the self-resonant frequency of the inductors, therefore parasitic



Fig. 2. (a) Concept of wireless inductive power link (b) Equivalent circuit

capacitance  $(C_1, C_2)$  are typically ignored in this case. Resonant inductive coupling, however, uses this capacitance to resonate with the inductors, increasing the flux linked between transmitter and receiver.

# B. Analysis with Equivalent Circuit

As shown in Fig. 3 (a), the circuit with a transformer can be converted to the equivalent circuit with the reflected load Ze. Ze captures the impact of the secondary part on the primary part. The reflected impedance Ze can be expressed by

$$Z_e = \frac{S^2 M^2}{Z_2} = \frac{R_{p2} k^2 Q_1 Q_2' + SM k^2 Q_1 Q_2'}{R_{p2} / R_1 + k^2 Q_1 Q_2'}$$
(1)

where  $Q_2' = \omega L_2/R_{p2} = \omega L_2/(R_L ||Q_2|^2 R_2)$ . The power consumed at Ze should be identical to the power transferred to the secondary part. Considering that the real part of (1) is the resistive component, we can derive the fraction of delivered power to secondary part at resonance. This is the power efficiency at the primary side,  $\eta_1$ .

$$\eta_1 = \frac{re(Z_e)}{R_1 + re(Z_e)} = \frac{k^2 Q_1 Q_2'}{1 + k^2 Q_1 Q_2' \left(1 + \frac{R_1}{R_{p2}}\right)}$$
(2)

At the secondary equivalent circuit, shown in Fig. 3 (b), the parasitic resistance can be converted into an equivalent parallel loss across the LC tank. The power from the primary part will be dissipated in both  $R_2$  and  $R_L$ , and the power consumed at  $R_L$  represents the net output power available at the receiver. At resonance, the power efficiency at the secondary part,  $\eta_2$  can be written as

$$\eta_2 = \frac{Q_2^2 R_2}{Q_2^2 R_2 + R_L} = \frac{Q_2}{Q_2 + Q_L}$$
(3)



Fig. 3. (a) Entire equivalent circuit (b) Secondary equivalent circuit

Combining (2) and (3), the total power efficiency of the inductive power link is derived as a form similar to [6-8].

$$\eta = \eta_1 \eta_2 = \frac{k^2 Q_1 Q_2}{1 + k^2 Q_1 Q_2 \left(1 + \frac{R_1}{R_{p_2}}\right)} \cdot \frac{Q_2}{Q_2 + Q_L}$$
(4)

## C. Maximum Power Transfer Efficiency

The power transfer efficiency can be maximized by adjusting conditions such as R, L, C of coils and  $R_L$  value. In practice, for planar integrated spiral inductors it is difficult to adjust the L, C, and R values of the coils independently, since all the values are partially correlated. Therefore,  $R_L$  is the best practical factor to adjust when optimizing the wireless link for a given coil. By differentiating (4) w.r.t.  $R_L$ , the optimal  $R_L$  can be obtained as

$$R_{L \, opt} = \frac{Q_2 R_2}{k} \tag{5}$$

This optimal condition makes the maximum power transfer efficiency a function of coupling coefficient k and quality factor of the coils, both of which may be optimized when designing the coils.

$$\eta_{Max} = \frac{k^2 Q_1 Q_2}{(kQ_1 + k^2 + 1)(kQ_2 + 1)} \tag{6}$$

With large values of k and Q, the power efficiency approaches 1 as expected.

## **III. POWER TRANSFER DENSITY**

While high power transfer efficiency is critical for low power systems, area-constrained systems can require larger power transfer through smaller area coils at an acceptable loss in efficiency. With a fixed distance between two coils, larger coils result in larger k and higher efficiency. However, using larger coils requires more silicon area, and it ultimately decreases the power transfer density. Therefore, a parallel power transfer scheme can be taken into consideration in order to increase power density and maximize the amount of power delivery through the same area, as illustrated in Fig. 4.



Fig. 4. Concept of parallel inductive power transfer (a) parallel power delivery using multiple maximum-power-density coils (b) single power delivery using one large coil

In order to compare the performance of single inductive power link to a parallel inductive power link, the power transfer density should be analyzed first.

# A. Output Delivered Power

Fig. 5 shows that the transformer circuit has the equivalent circuit with reflected impedance and parallel resistance. The reflected impedance is split into the imaginary and real part, and the real resistive part is converted to parallel resistance using quality factor  $Q_p = \omega L_1/(R_1 + re(Z_e))$ .

At resonance, the input power is given by

$$P_{i} = \frac{1}{2} \left( \frac{|V_{S}|^{2}}{Q_{p}^{2} (R_{1} + re(Z_{e}))} \right)$$
(7)

and the output power can be written as

$$P_{o} = \eta P_{i} = \eta_{1} \eta_{2} P_{i}$$

$$= \frac{1}{2} \cdot \frac{Q_{2}^{2} R_{2}}{Q_{2}^{2} R_{2} + R_{L}} \cdot \frac{re(Z_{e})}{R_{1} + re(Z_{e})} \cdot \frac{|V_{S}|^{2}}{Q_{p}^{2}(R_{1} + re(Z_{e}))}$$

$$= \frac{1}{2} \cdot \frac{Q_{2}^{2} R_{2}}{Q_{2}^{2} R_{2} + R_{L}} \cdot \frac{k^{2} |V_{S}|^{2}}{Z_{2}}$$
(8)

## B. Optimal Load

The power transfer also can be maximized by adjusting the  $R_L$  value. By differentiating (8) w.r.t.  $R_L$  at resonance, the optimal  $R_L$  can be expressed as

$$R_{L opt} = Q_2^2 R_2 (1 - k^2) \tag{9}$$

Substituting the optimal  $R_L$  into (8), we get the maximum power transfer amount as



Fig. 5. Equivalent circuit for power density calculation

$$P_{o Max} = \frac{1}{8} \frac{k^2}{R_2(1+k^2)} |V_S|^2 \tag{10}$$

# C. Power Transfer Density

The power transfer density is defined as the amount of available transferred power per the unit area. Assuming square-shaped, planar spiral coils are used with diameter d, the power transfer density will be a function of d. In addition, coupling coefficient k is also the function of d [9].

$$k = \left(\frac{d^2}{12x^2 + d^2}\right)^{1.5} \tag{11}$$

where x is the distance between coils. With (11), the power transfer density is given by

$$P_{Den} = \frac{P_{oMax}}{d^2} = \frac{1}{8} \frac{k^2}{d^2 R_2 (1+k^2)} |V_S|^2$$
$$= \frac{1}{8} \frac{|V_S|^2}{R_2} \cdot \frac{d^4}{(12x^2+d^2)^3+d^6}$$
(12)

By differentiating (10) w.r.t. d, the optimal size of the coils and corresponding k can be found as the function of the separation between coils, x. For instance, when  $x=15\mu$ m, the optimal d is 58 $\mu$ m, and k is equal to 0.41.

## **IV. SIMULATION RESULTS**

## A. Simulation Setup

To verify this model, we designed planar spiral coils using a Chartered  $0.13\mu$ m CMOS process. Fig. 6 shows the simulation setup of two identical square coils vertically stacked to implement the inductive power link through stacked ICs. We sweep the separation *x*, and the diameter *d* to test power efficiency and density. HFSS is used to extract the lumped-element models for coils, and these models are imported to Sperctre to simulate the inductive power link.

## B. Power Transfer Efficiency

As shown in (6), the maximum power transfer efficiency strongly depends on k. To show this dependency, we swept the

	TABLE I DETAILS OF COILS	
	Value	
Parameter	Power	Power
	Efficiency	Density
Diameter d	60µm	20~120µm
Distance <i>x</i>	5~30µm	15µm
Width	0.65µm	0.65~1.5µm
Space	0.35µm	0.35~2.0µm
Number of turns	5	5
Number of layers	4	4
$\mathcal{Q}$	3.92	1.27~4.16
freq <sub>res</sub>	3.75GHz	1.33~10.1GHz
k	0.432	0.046~0.773



Fig. 6. Two vertically stacked coils for wireless inductive power link



Fig. 7. Coupling coefficient k vs. power transfer efficiency

distance x from 5µm to 30µm with 60µm-sized coils. It maintains a *Q*-factor of 3.9 while k varies from 0.125 to 0.887. Fig. 7 shows the simulation results of the maximum power transfer efficiency when using the optimal load resistance. The simulation values match the theoretical values well. As



Fig. 8. (a) The coil diameter vs. coupling coefficient k and the optimal  $R_L$  (b) coupling coefficient k vs. power transfer amount and power transfer density

expected, higher k results in higher power transfer efficiency. When k=0.887 (60µm coils, 5µm separation), we can achieve a power transfer efficiency of 52%.

## C. Power Transfer Density

To verify the power transfer density model, we designed 11 coupled coils which have varying diameters from  $20\mu$ m to  $120\mu$ m in  $10\mu$ m steps. The distance between the paired coils is fixed at  $15\mu$ m, which can be reasonably achieved with face-to-face stacking of two CMOS die. Over this range, *k* varies from 0.05 to 0.77, as shown in Fig. 8 (a). With the specific dimensions, we can calculate *k* and the optimal  $R_L$  by (9) and (11) respectively, and the theoretical values match the simulation results.

Fig. 8 (b) shows the maximum delivered power amount and power transfer density depending on k. As mentioned in Section III, when the separation  $x=15\mu$ m, the optimal coil size for the maximum power density is 58 $\mu$ m and k is 0.41. The simulation result verifies this; the optimal k is about 0.35 and



Fig. 9. Simulation setup for parallel inductive power link (a) 3x3 array of  $60\mu m x 60\mu m$  coils (b) 2x2 array of  $90\mu m x 90\mu m$  coils (c) single  $200\mu m x 200\mu m$ 

the optimal size is about  $55\mu m$ . The maximum power transfer density is  $49mW/mm^2$ .

# D. Performance Comparison

In order to compare the performance between parallel and single inductive power links, we simulated the power efficiency and maximum power transfer for the three configurations shown in Fig. 9. Assuming the same area of  $200\mu m \times 200\mu m$ , we assigned a 3x3 array of  $60\mu m \times 60\mu m$  coils (optimal power density), a 2x2 array of  $90\mu m \times 90\mu m$ , and a single  $200\mu m \times 200\mu m$  coil (maximum power efficiency). The separation of the stacked coils is 15 µm. The results are shown in Fig. 10. Since the single  $200\mu m \times 200\mu m$  coil has the largest *k*, it has the highest power efficiency of 52%. However, the total delivered power amount becomes the largest with the 3x3 array because  $60\mu m \times 60\mu m$  coil has the highest power density. A simulated power transfer of 1.48mW was achieved over the link, which is five times larger than the single inductive power link.

# V. CONCLUSION

The performance of a wireless inductive power link can be improved by using resonant inductive coupling. For low power



Fig. 10. Simulation results: power transfer efficiency, total delivered amount, and power transfer density of three cases

systems and high power efficiency, higher k and Q are required. However, in order to increase the absolute power transfer amount, power density is critical, and the optimal value of k to maximize power density depends on the distance and coil technology. Therefore, the parallel inductive power link with the optimal sized coils can deliver more power than the single inductive power link can while the latter has higher efficiency.

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